



Rev.01 - 06 July 2022

Product data sheet

1. General description

Hyperfast power diode (Bare die).

2. Features and benefits

- · Fast switching and soft reverse recovery characteristics
- Low forward voltage drop
- Low leakage current
- Low reverse recovery current
- · Reduces switching losses in associated MOSFET or IGBT

3. Quick reference data

Table	1.	Quick	reference	data
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Symbol	Parameter	Conditions	Notes	Values		Unit	
V_{RRM}	repetitive peak reverse voltage		[1]	600		V	
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse	[2]		75		А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 75 A; T _j = 25 °C	[2]	-	2.20	2.75	V
Dynamic	characteristics						
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	[2]	-	-	50	ns

4. Ordering information

Table 2. Ordering information

Product type	Orderable part number	Description	Packing method
WB75FC60AL	WB75FC60ALZ	Bare die on wafer	Unsawn wafer, Vacuum packing

Hyperfast power diode - Bare die

5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage		[1]	600	V
V _{RWM}	crest working reverse voltage		[1]	600	V
V _R	reverse voltage	DC	[1]	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse	[2]	75	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 µs; square-wave pulse	[2]	150	А
I _{FSM}		$t_{\rm p}$ = 10 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse	[2]	700	А
current	current	$t_{\rm p}$ = 8.3 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse	[2]	750	А
Tj	junction temperature			-40 to 175	°C

6. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
V _F	forward voltage	I _F = 75 A; T _j = 25 °C	[2]	-	2.20	2.75	V
		I _F = 75 A; T _j = 150 °C	[2]	-	1.60	2.10	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	[1]	-	-	10	μA
		V _R = 600 V; T _j = 125 °C	[2]	-	-	1	mA
Dynamic	characteristics			,			
Q _r	reverse charge	I _F = 75 A; V _R = 400 V; dI _F /dt = 200 A/ μs; T _j = 25 °C	[2]	-	85	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	[2]	-	-	50	ns
		$I_F = 75 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_1 = 25 \text{ °C}$	[2]	-	42	-	ns

Notes:

[1] means that parameter are 100% test at $T_{\! amb}$ = 25°C

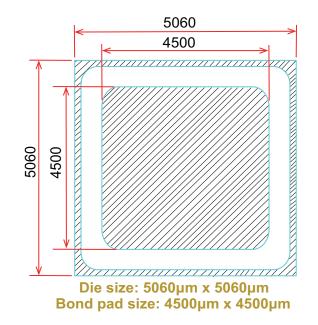
[2] means that the guaranteed ratings and parameter limits will depend on the assembled structure. When correctly assembled with suitable die bonding and wire bonding, the device will have ratings and characteristics guaranteed in this data sheet, similar to the assembled devices.

WB75FC60AL

Hyperfast power diode - Bare die

MECHANICAL SPECIFICATIONS			
Chip size	5.06 x 5.06	mm²	
Anode pad size	4.5 x 4.5	mm²	
Area total / active	25.6 / 20.25	mm²	
Thickness	300	μm	
Wafer size	125	mm	
Scribe line	80	μm	
Max possible chips per wafer	418	pcs	
Passivation	Glass / Trough		
Front metal	AI (10)	μm	
Back metal	Ti/Ni/Ag (0.1/0.3/0.15)	μm	

CHIP LAYOUT



WB75FC60AL

Hyperfast power diode - Bare die

7. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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